

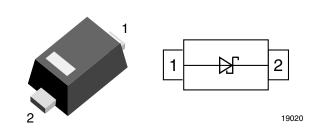
Vishay Semiconductors



Small Signal Schottky Diode

Features

- This diode features very low turn-on voltage and fast switching.
- This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- Space saving SOD-523 package
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



Mechanical Data

Case: SOD-523

Molding Compound Flammability Rating:

UL 94 V-0

Terminals: High temperature soldering guaranteed: 260 °C/10 s at terminals

Weight: approx. 1.6 mg

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Parts Table

Part	Ordering code	Marking	Remarks	
BAS520-02V	BAS520-02V-GS18 or BAS520-02V-GS08	Т	Tape and Reel	

RoHS

COMPLIANT

Absolute Maximum Ratings

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage		V _{RRM}	30	V	
Forward continuous current		١ _F	200	mA	
Power dissipation		P _{tot}	200	mW	

Thermal Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol Value		Unit
Junction soldering point		R _{thJS}	100	K/W
Junction temperature		Tj	125	°C
Storage temperature range		T _{stg}	- 55 to +150	°C

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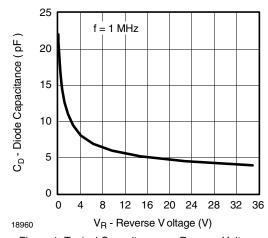
Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

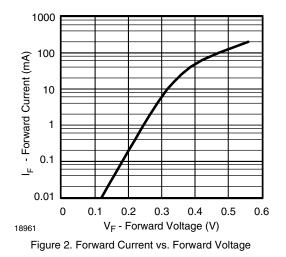
Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	$I_R = 1 \ \mu A \ (pulsed)$	V _(BR)	30			V
Leakage current	Pulse test V _R = 30 V, t_p < 300 μ s	I _R		0.5	1	μA
Forward voltage	Pulse test t _p < 300 μs, I _F = 1.0 mA	V _F			320	mV
	Pulse test t _p < 300 μs, I _F = 200 mA,	V _F			600	mV
Diode capacitance	V _R = 0 V, f = 1 MHz	CD		25	30	pF
Reverse recovery time	$I_{F} = 10 \text{ mA}, I_{R} = 10 \text{ mA},$ $I_{rr} = 1 \text{ mA}, R_{L} = 100 \Omega$	t _{rr}		10		ns

Typical Characteristics

T_{amb} = 25 °C unless otherwise specified







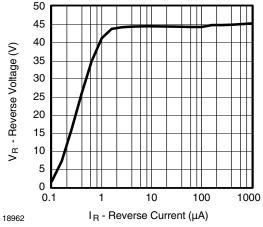


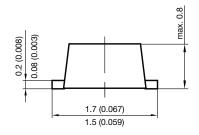
Figure 3. Typical Reverse Voltage vs. Reverse Current

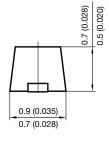


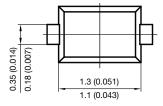
BAS520-02V

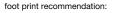
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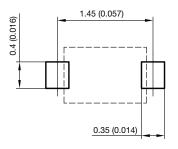
Package Dimensions in millimeters (inches): SOD-523











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